## NSN 5961-01-317-8656

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-317-8656 **Inclosure Material:** Metal and ceramic **Overall Length:** Between 0.205 inches and 0.225 inches **Overall Diameter:** Between 0.119 inches and 0.124 inches **Function For Which Designed:** Voltage variable capacitor **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, instantaneous **Capacitance Rating In Picofarads:** 6.8 **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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